

## High-Voltage Surface Mount Schottky Rectifier

High Barrier Technology for improved high temperature performance

### Major Ratings and Characteristics

$I_{F(AV)}$	2.0 A
$V_{RRM}$	90 V, 100 V
$I_{FSM}$	75 A
$V_F$	0.65 V
$I_R$	10 $\mu$ A
$T_j$ max.	175 °C



DO-214AA (SMB)

### Features

- Low profile package
- Guardring for overvoltage protection
- Ideal for automated placement
- Low power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High surge capability
- Meets MSL level 1, per J-STD-020C
- Solder Dip 260 °C 40 seconds



### Mechanical Data

**Case:** DO-214AA (SMB)

Epoxy meets UL 94V-0 Flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified)

**Polarity:** Color band denotes the cathode end

### Typical Applications

For use in low voltage high frequency inverters, free-wheeling, dc-to-dc converters, and polarity protection applications

### Maximum Ratings

$T_A = 25$  °C unless otherwise specified#

Parameter	Symbol	SS2H9	SS2H10	Unit
Device marking code		MS9	MS10	
Maximum repetitive peak reverse voltage	$V_{RRM}$	90	100	V
Working peak reverse voltage	$V_{RWM}$	90	100	V
Maximum DC blocking voltage	$V_{DC}$	90	100	V
Maximum average forward rectified current at: $T_L = 130$ °C	$I_{F(AV)}$	2.0		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	75		A
Peak repetitive reverse surge current at $t_p = 2.0$ $\mu$ s, 1 KHz	$I_{RRM}$	1.0		A
Voltage rate of change (rated $V_R$ )	dv/dt	10000		V/ $\mu$ s
Operating junction and storage temperature range	$T_J, T_{STG}$	- 65 to + 175		°C

### Electrical Characteristics

$T_A = 25\text{ }^\circ\text{C}$  unless otherwise specified#

Parameter	Test condition	Symbol	SS2H9	SS2H10	Unit
Maximum instantaneous forward voltage at <sup>(1)</sup> :	$I_F = 2.0\text{ A}, T_J = 25\text{ }^\circ\text{C}$	$V_F$	0.79		V
	$I_F = 2.0\text{ A}, T_J = 125\text{ }^\circ\text{C}$		0.65		
Maximum DC reverse current at rated DC blocking voltage <sup>(1)</sup>	$T_J = 25\text{ }^\circ\text{C}$	$I_R$	10		$\mu\text{A}$
	$T_J = 125\text{ }^\circ\text{C}$		4		

Notes:

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

### Thermal Characteristics

$T_A = 25\text{ }^\circ\text{C}$  unless otherwise specified

Parameter	Symbol	SS2H9	SS2H10	Unit
Maximum thermal resistance junction to lead $T_L = 25\text{ }^\circ\text{C}^{(1)}$	$R_{\theta JA}$	80		$^\circ\text{C/W}$
	$R_{\theta JL}$	25		

Notes:

(1) Units mounted on P.C.B. with 0.2 x 0.2" (5.0 x 5.0 mm) copper pad areas

### Ratings and Characteristics Curves

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

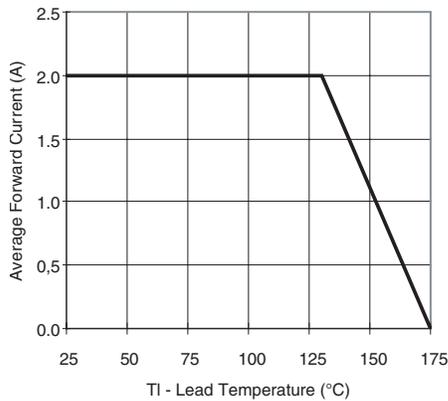


Figure 1. Forward Current Derating Curve

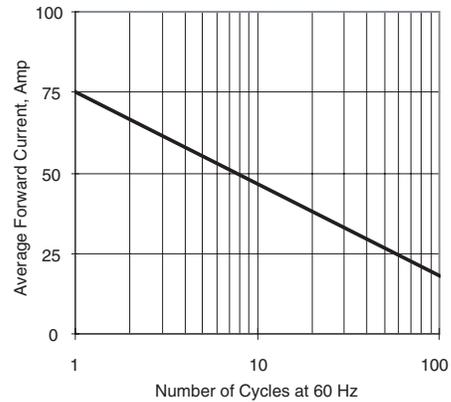


Figure 2. Max Non-Repetitive Peak FWD Surge Current

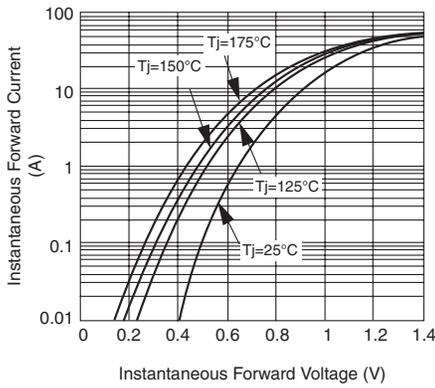


Figure 3. Typical Instantaneous Forward Characteristics

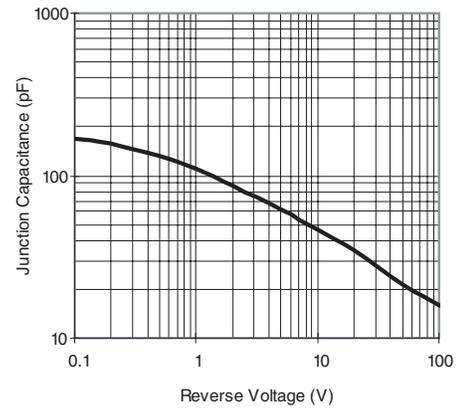


Figure 5. Typical Junction Capacitance

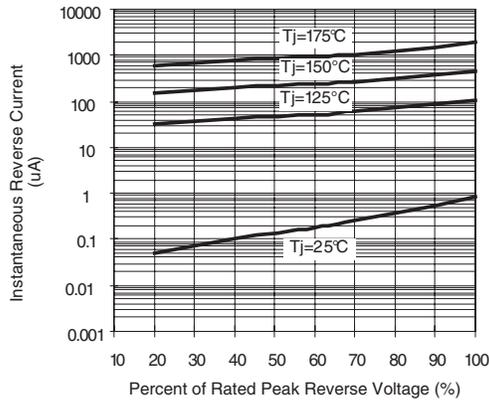


Figure 4. Typical Reverse Characteristics

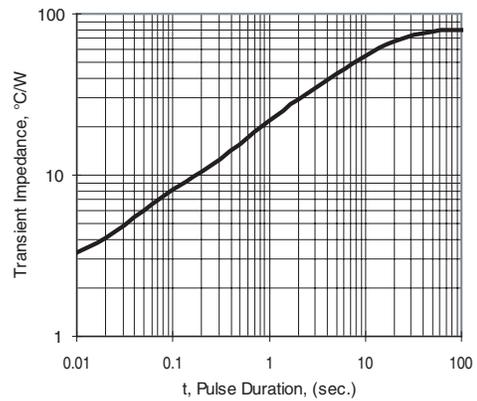


Figure 6. Typical Transient Thermal Impedance Per Leg

## Package outline dimensions in inches (millimeters)

